

Docket No.: 1248-0772PUS1

(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:

Akiyoshi FUJII et al.

Application No.: Not Yet Assigned

Confirmation No.: N/A

Examiner: Not Yet Assigned

Filed: February 25, 2005

Art Unit: N/A

For: TFT ARRAY SUBSTRATE, LIQUID CRYSTAL

DISPLAY DEVICE, MANUFACTURING METHODS

OF TFT ARRAY SUBSTRATE AND LIQUID

CRYSTAL DISPLAY DEVICE, AND ELECTRONIC

DEVICE

LETTER

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

The PTO is requested to use the amended sheets/claims attached hereto (which correspond to Article 19 amendments or to claims attached to the International Preliminary Examination Report (Article 34)) during prosecution of the above-identified national phase PCT application.

If necessary, the Commissioner is hereby authorized in this, concurrent, and future replies to charge payment or credit any overpayment to Deposit Account No. 02-2448 for any additional fees required under 37.C.F.R. §1.16 or 1.14; particularly, extension of time fees.

Dated: February 25, 2005

Respectfully submitte

TCB/smt

Terrell C. Birch

Attachment(s)

Registration No.: 19,382

BIRCH, STEWART, KOLASCH & BIRCH, LLP

8110 Gatehouse Rd Suite 100 East P.O. Box 747

Falls Church, Virginia 22040-0747

(703) 205-8000

Attorney for Applicant

PATENT COOPERATION TREATY

PCT

INTERNATIONALPRELIMINARYREPORTONPATENTABILITY

(Chapter II of the Patent Cooperation Treaty)

(PCT Article 36 and Rule 70)

Applicant's or agent's file reference 03R00325	FOR FURTHER ACT	ION	See Form PCT/IPEA/416				
International application No.	International filing date (a	lay/month/year)	Priority date (day/month/year)				
PCT/JP 03 / 11057	29.08.	2003	30.08.2002				
· ·	International Patent Classification (IPC) or national classification and IPC						
Int.Cl 7 H01L29/786,H01L	21/336,G02F1/	L368,G09F9/	00				
		•					
Applicant	1 ::						
SHARP KABUSI	IIKI KAISHA						
This report is the international particle 35 and to the international particle 35 and t	preliminary examination r	eport, established by according to Article	this International Prelimi	nary Examini	ng		
2. This REPORT consists of a total	_	ncluding this cover sh					
3. This report is also accompanied	by ANNEXES, comprising	g :		,			
a. a total of 2	_sheets, as follows:		•		•		
1 IV 1	•		een amended and are the barrier (see Pule 70.16 and S	-			
	e Instructions).	morized by this Auth	ority (see Rule 70.16 and S	COUCH OUT OF I	ше		
			y considers contain an ame as indicated in item 4 of Bo				
Supplemental		application as mou,	III IIII 7 01 DC	mie tii	-		
	e and number of electroni			indiant die	,		
			iter readable form only, as he Administrative Instruct		me		
4. This report contains indications	relating to the following ite	ems:					
Box No. I Basis of the	ne report						
Box No. II Priority							
Box No. III Non-estab	lishment of opinion with r	egard to novelty, inve	entive step and industrial a	pplicability			
Box No. IV Lack of ur	nity of invention			•			
Box No. V Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement					ty;		
Box No. VI Certain documents cited							
Box No. VII Certain de	Box No. VII Certain defects in the international application						
Box No. VIII Certain observations on the international application							
Date of submission of the demand Date of completion of this report							
01.03.2004 22.11.2004							
Name and mailing address of the IPEA/JP Authorized officer 4M 29					34		
Japan Patent Of	TAKASHI	WATAHIKI					
3-4-3 Kasumigaseki Chiyoda-ku Tokyo 100-8915 Japan Telephone No. +81-3-3581-1101 Ext. 3460							
3-4-3, Kasumigaseki, Chiyoda-ku, Tokyo 100-8915, Japan Telephone No. 781-3-3581-1101 Ext. 3400							

Form PCT/IPEA/409 (cover sheet) (January 2004)

International application No.

PCT/JP03 /11057

Box No. I	o. I Basis of the report	
1. With	ith regard to the language, this report is based on the international application in the language in which	it was filed, unless
others	herwise indicated under this item.	
	This report is based on translations from the original language into the following language which is the language of a translation furnished for the purposes of:	
	international search (under Rules 12.3 and 23.1(b))	
	publication of the international application (under Rule 12.4)	
	international preliminary examination (under Rules 55.2 and/or 55.3)	
furnis	ith regard to the elements of the international application, this report is based on (replacement shee raished to the receiving Office in response to an invitation under Article 14 are referred to in this report d are not annexed to this report):	
	the international application as originally filed/furnished	
	the description:	
	pages 1-120 as origin	nally filed/furnished
	pages* received by this Authority on	·
	pages* received by this Authority on	
. 🗔	7	
	the claims: pages 122-134 as origin	nally filed/furnished
	pages* as amended (together with any stateme received by this Authority on 12.08.2	
	pages* received by this Authority on	
	the drawings:	
	pages 1/35-35/35 as origin	
	pages* received by this Authority on	
	pages* received by this Authority on	<u></u>
	a sequence listing and/or any related table(s) - see Supplemental Box Relating to Sequence Listing	ng.
3.	The amendments have resulted in the cancellation of:	
	the description, pages	
	the claims, Nos.	
	the drawings, sheets/figs	
	the sequence listing (specify):	
	any table(s) related to sequence listing (specify):	
4.	This report has been established as if (some of) the amendments annexed to this report and listed made, since they have been considered to go beyond the disclosure as filed, as indicated in the (Rule 70.2(c)). the description, pages	below had not been Supplemental Box
	the claims, Nos.	
	the drawings, sheets/figs	
	the sequence listing (specify):	
1	any table(s) related to sequence listing (specify):	•
* If item	tem 4 applies, some or all of those sheets may be marked "superseded."	

International application No. PCT/JP03 / 11057

Box No. V Reasoned statement u citations and explanat		e 35(2) with regard to novelty, inventive step or industrial apring such statement	plicability;
. Statement			
Novelty (N)	Claims	2-35	YES
•	Claims	1	NO
Inventive step (IS)	Claims	3,7,8,11-18,21,25-33,35	YES
• ` '	Claims	1,2,4-6,9,10,19,20,22-24,34	NO
Industrial applicability (IA)	Claims	1-35	YES
	Claims		NO

2. Citations and explanations (Rule 70.7)

D1:WO 99/39373 A2(TRUSTEES OF PRINCETON UNIVERSITY)1999.08.05 whole document, Figs.14A,14B

& JP 2002-502098 A, whole document, Figs.14A,14B

& EP 1051738 A & US 6087196 A1 & AU 2481599 A

D2: WO 97/43689 A1(SEIKO EPSON CORPORATION)1997.11.20,

whole document, Fig.4

& EP 855614 A1 & US 5989945 A1 & TW 449670 B

D3: EP 930641 A2(SEIKO EPSON CORPORATION)1999.07.21,

whole document, Figs.1-20

& JP 11-204529 A, whole document, Figs.1-20 & TW 383280 B

[Claim 1]

The subject matter of claim 1 does not appear to be novel with respect to the D1 cited in the ISR. Claim 1 is amended by inserting "processed" between "the" and "semiconductor layer". But the meaning of "processed" is not specified in Claim 1. Therefore, "semiconducting layer 122" described in D1 is correspond to "processed semiconductor layer" in this application.

[Claims 2,4,10,19,20,34]

The subject matter of claims 2,4,10,19,20 and 34 does not appear to involve an inventive step in view of the D1. The technology which forms a gate electrode of a main line and a branch electrode is a well-known technology.

[Claims 5,6,9]

The subject matter of claims 5,6 and 9 does not appear to involve an inventive step in view of the D1. To form semiconductor layer in the exact position (= near gate, source and drain electrode) is obvious to a person skilled in the art.

[Claims 22-24]

The subject matters of claims 22-24 do not appear to involve an inventive step in view of the D2 and the D3 cited in the ISR. The technologies of forming a convex guide and forming a lyophilic area and a lyophobic area to keep a droplet within the electrode area are known technologies.(see D3) The person skilled in the art would easily conceive the idea of applying these technologies to the invention disclosed in the D2.

International application No. PCT/JP 03 /11057

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In case the space in any of the preceding boxes is not sufficient. Continuation of: Box No. V

[Claims 3,7,8,11-18,21,25-33,35]

The subject matters of claims 3,7,11-18,21,25-33 and 35 are neither disclosed in any of the documents cited in the ISR nor obvious to a person skilled in the art.

International application No. PCT/JP03 /11057

Box	Box No. VI Certain documents cited						
1.	Certain published docum	ents (Rule	70.10)				
	Application No. Patent No.		Publication date (day/month/year)	Filing date (day/month/year)	Priority date (valid claim) (day/month/year)		
	JP 2003-3181	92 A	07.11.2003	22.04.2002			

2. Non-written disclosures (Rule 70.9)

Kind of non-written disclosure

Date of non-written disclosure (day/month/year)

Date of written disclosure referring to non-written disclosure (day/month/year)

CLAIMS

1. (amended) A TFT array substrate, comprising:

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a thin film transistor section in which a gate electrode is formed on a substrate, and a semiconductor layer is formed on the gate electrode via a gate insulation layer,

the <u>processed</u> semiconductor layer having a shape formed by dropping a droplet.

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2. The TFT array substrate as set forth in claim 1, wherein:

the gate electrode in the thin film transistor section is a branch electrode which is branched out of a main line of the gate electrode, and the branch electrode has an open end protruded from an area for the semiconductor layer.

3. The TFT array substrate as set forth in claim 2, wherein:

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the branch electrode is arranged so that a portion protruded from the area for the semiconductor layer is smaller in width than a portion confined within the area for the semiconductor layer.

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4. The TFT array substrate as set forth in claim 2,

- 121/1 -

wherein: